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View Online at https://aerobasegroup.com/nsn/5961-01-281-5026 **Inclosure Material:** Metal **Overall Length:** 1.450 inches **Function For Which Designed:** Voltage regulator **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Thread Size:** 0.250 inches **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 16.0 regulator voltage **Voltage Tolerance In Percent:** -1.0/+1.0**Current Rating Per Characteristic:** 780.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo4004 **Thread Series Designator: Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Reference Number Differentiating Characteristics:** Breference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp. Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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